

Vishay General Semiconductor

AUTOMOTIVE GRADE

COMPLIANT

HALOGEN FREE

Surface-Mount PAR® Transient Voltage Suppressors

High Temperature Stability and High Reliability Conditions







LINKS TO ADDITIONAL RESOURCES









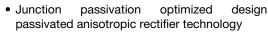


PRIMARY CHARACTERISTICS				
V _{BR}	12 V to 100 V			
V_{WM}	10.2 V to 85.5 V			
P _{PPM} (10 x 1000 μs)	2000 W			
T _J max.	185 °C			
Polarity	Bidirectional			
Package	DFN6546A			
Circuit configuration	Single			

FEATURES

- Low-profile package typical height of 0.88 mm
- Leadless DFN package with side-wettable flanks suitable for customer AOI (Automatic Optical Inspection)





- T_J = 185 °C capability suitable for high reliability and automotive requirement
- Bidirectional
- Excellent clamping capability
- Peak pulse power: 2000 W (10/1000 μs)
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
 - Automotive ordering code: base P/NHM3
- · Compatible to SMPC (TO-277A) package case outline
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

TYPICAL APPLICATIONS

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lightning on ICs, MOSFET, signal lines of sensor units for automotive.

MECHANICAL DATA

Case: DFN6546A

Molding compound meets UL 94 V-0 flammability rating Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

ALO-Q TO T qualified

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

HM3 suffix meets JESD 201 class 2 whisker test **Polarity:** no cathode band for bidirectional types

MAXIMUM RATINGS (T _A = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	VALUE	UNIT		
Peak pulse power dissipation with a 10/1000 µs waveform (fig. 1) (1)	P _{PPM}	2000	W		
Peak pulse current with a 10/1000 µs waveform (fig. 3) (1)	I _{PPM}	See table next page	Α		
Operating junction and storage temperature range	T _J , T _{STG}	-65 to +185	°C		

Note

 $^{(1)}$ Non-repetitive current pulse, per fig. 3 and derated above T_A = 25 $^{\circ}$ C per fig. 2

T2KN12CA thru T2KN100CA

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C, unless otherwise noted)											
DEVICE MARKING CODE	BREAKDOWN		TEST CURRENT I _T (mA)	STAND- OFF VOLTAGE V _{WM} (V)	MAXIMUM REVERSE LEAKAGE AT V _{WM} I _R (μA)	MAXIMUM REVERSE LEAKAGE AT V _{WM} T _J = 150 °C I _R	MAXIMUM PEAK PULSE SURGE CURRENT I _{PPM} ⁽²⁾ (A)	MAXIMUM CLAMPING VOLTAGE AT I _{PPM} V _C (V)	TYPICAL TEMP. COEFFICIENT OF V _{BR} ⁽³⁾ αT (%/°C)		
		MIN.		MAX.				(μΑ)	(F-y	(•)	(70, 0)
T2KN12CA	T2NA	11.4	12.0	12.6	1.0	10.2	5.0	50	120	16.7	0.070
T2KN13CA	T2NB	12.4	13.0	13.7	1.0	11.1	5.0	50	110	18.2	0.072
T2KN15CA	T2NC	14.3	15.0	15.8	1.0	12.8	2.0	20	94.3	21.2	0.076
T2KN16CA	T2ND	15.2	16.0	16.8	1.0	13.6	2.0	20	88.9	22.5	0.078
T2KN18CA	T2NE	17.1	18.0	18.9	1.0	15.3	1.0	10	78.4	25.5	0.080
T2KN20CA	T2NF	19.0	20.0	21.0	1.0	17.1	1.0	10	72.2	27.7	0.082
T2KN22CA	T2NG	20.9	22.0	23.1	1.0	18.8	1.0	10	65.4	30.6	0.084
T2KN24CA	T2NH	22.8	24.0	25.2	1.0	20.5	1.0	10	60.2	33.2	0.085
T2KN27CA	T2NJ	25.7	27.0	28.4	1.0	23.1	1.0	10	53.3	37.5	0.087
T2KN30CA	T2NK	28.5	30.0	31.5	1.0	25.6	1.0	10	48.3	41.4	0.088
T2KN33CA	T2NL	31.4	33.0	34.7	1.0	28.2	1.0	10	43.8	45.7	0.089
T2KN36CA	T2NM	34.2	36.0	37.8	1.0	30.8	1.0	10	40.1	49.9	0.090
T2KN39CA	T2NN	37.1	39.0	41.0	1.0	33.3	1.0	10	37.1	53.9	0.091
T2KN43CA	T2NP	40.9	43.0	45.2	1.0	36.8	1.0	10	33.7	59.3	0.092
T2KN47CA	T2NQ	44.7	47.0	49.4	1.0	40.2	1.0	10	30.9	64.8	0.092
T2KN51CA	T2NR	48.5	51.0	53.6	1.0	43.6	1.0	10	28.5	70.1	0.093
T2KN56CA	T2NS	53.2	56.0	58.8	1.0	47.8	1.0	10	26.0	77.0	0.093
T2KN62CA	T2NT	58.9	62.0	65.1	1.0	53.0	1.0	10	23.5	85.0	0.094
T2KN68CA	T2NU	64.6	68.0	71.4	1.0	58.1	1.0	10	21.7	92.0	0.095
T2KN75CA	T2NV	71.3	75.0	78.8	1.0	64.1	1.0	10	19.2	104	0.095
T2KN82CA	T2NW	77.9	82.0	86.1	1.0	70.1	1.0	10	17.7	113	0.095
T2KN91CA	T2NX	86.5	91.0	95.5	1.0	77.8	1.0	10	16.0	125	0.096
T2KN100CA	T2NY	95.0	100	105	1.0	85.5	1.0	10	14.6	137	0.096

Notes

- ⁽¹⁾ Pulse test: $t_p \le 50 \text{ ms}$
- (2) Surge current waveform per fig. 3 and derated per fig. 2
- (3) To calculate V_{BR} vs. junction temperature, use the following formula: V_{BR} at T_J = V_{BR} at 25 °C x (1 + αT x (T_J 25))
- (4) All terms and symbols are consistent with ANSI/IEEE C62.35

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	UNIT			
Thermal resistance	R _{θJA} ⁽¹⁾	76	95	°C/W	
	R _{0JM} (2)	1.2	1.5	°C/W	

Notes

- (5) Thermal resistance junction-to-ambient to follow JEDEC® 51-2A, device mounted on FR4 PCB, 2 oz., 4.8 mm x 4.72 mm
- (6) Thermal resistance junction-to-mount to follow JEDEC® 51-14 using transient dual interface test method (TDIM)

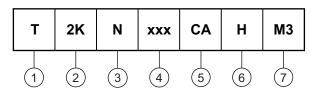
IMMUNITY TO STATIC ELECTRICAL DISCHARGE TO THE FOLLOWING STANDARDS ($T_A = 25~^{\circ}\text{C}$ unless otherwise noted)					
STANDARD	TEST TYPE	TEST CONDITIONS	SYMBOL	VALUE	
IEC 61000-4-2	Contact discharge	$C = 150 \text{ pF}, R = 330 \Omega$	ESD	30 kV	
	Air discharge	C = 150 pr, h = 550 \$2	ESD	30 kV	

T2KN12CA thru T2KN100CA

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ORDERING INFORMATION TABLE

Device code



- 1 Vishay PAR® TVS product
- Peak pulse power rating (2K = 2000 W)
- Package type (N = DFN package)
- 4 Nominal breakdown voltage
- **5** Breakdown voltage tolerance and polarity (CA ± 5 %, bidirectional)
- 6 Quality grade (H = AEC-Q101 qualified, otherwise = industry grade)
- Material / Environment category (M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free)

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
T2KN12CAHM3/H (1)	0.094	Н	1500	7" diameter plastic tape and reel		
T2KN12CAHM3/I (1)	0.094	I	6000	13" diameter plastic tape and reel		

Note

(1) AEC-Q101 qualified

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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C, unless otherwise noted)

10 000

1000

100

10 20

C_J - Junction Capacitance (pF)

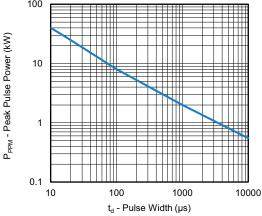


Fig. 1 - Peak Pulse Power Rating Curve

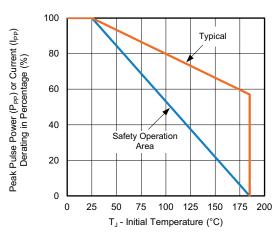


Fig. 2 - Pulse Power or Current vs. Initial Junction Temperature

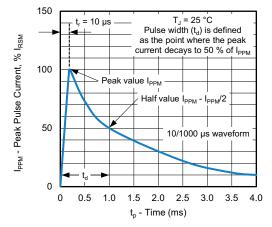
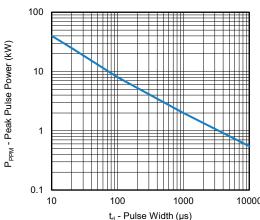


Fig. 3 - Pulse Waveform



V_{BR} - Breakdown Voltage (V) Fig. 4 - Typical Junction Capacitance

60

= 25 °C 1.0 MHz = 50 mV

70 80

sured at stand-off

40 50

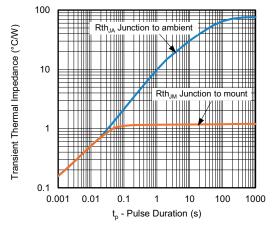


Fig. 5 - Typical Transient Thermal Impedance

Note

· Fig. 1, power calculations is based on IPPM times defined maximum clamping voltage by pulse width

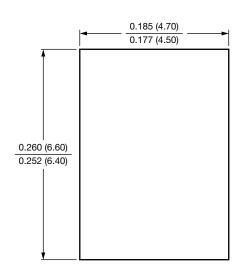


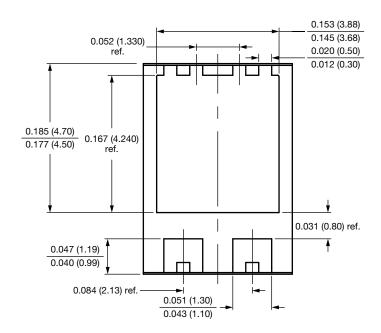


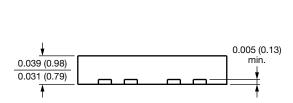
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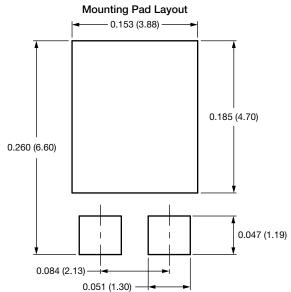
PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

DFN6546A











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